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Non-Isolated Boost Converter Based on Voltage Lift Technique

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ABSTRACT: Now a day, use of non-isolated boost converter has increased with the development in renewable energy sources. An isolated dc-dc converter uses a transformer to eliminate the dc path between its input and output. In contrast, a non-isolated dc-dc converter has a dc path between its input and output. The free current ripple, direct connection of inductor to input voltage source, less stress of elements and providing infinite voltage gain for duty cycle near to one are the theoretical advantages of the conventional non isolated boost converter. While, the electromagnetic interface, overvoltage problem on switch, reverse recovery problem and stability are disadvantages of conventional non isolated boost dc-dc converter as its duty cycle is limited to 0.8. There are few techniques to overcome these drawbacks and to improve voltage gain. This includes Switched Capacitor Technique, Interleaving Technique, Combination Technique, Voltage Lift Technique. The voltage lift technique is popular technique so as to increase the output voltage by using storage elements features. Also the current and voltage stress on elements are reduced to acceptable value which ultimately improves stability and circuit characteristics. This technique can be used in more boosting applications such as electrical vehicles, medical equipment, portable devices, etc.

KEYWORDS; Nonisolated; boost converter; dc-dc converter; voltage lift technique; high voltage gains.

I. INTRODUCTION

In recent years, power generation based on renewable energy sources have rapidly developed. This type of generation system is composed of sources like fuel cells, Photovoltaic (PV) cells and wind power. But fuel cells and PV cells are low voltage source to provide enough DC voltage for generating ac voltage. So PV cells can be connected in series to obtain sufficient DCvoltage. However, sufficient staking of cells is not possible in many high voltage applications and it is also difficult to avoid shadow effect. Hence, high step up DC-DC converters are usually used as the front end converters to step from low voltage to high voltage which are required to have a large conversion ratio, high efficiency and small volume.

In addition to above mentioned applications, a high step up DC-DC converter is also required by many applications such as, LED Lighting System, Portable Devices, Electrical Vehicles, Power factor correction, Uninterrupted Power Supply

Theoretically, high step up voltage gain with an extremely high duty cycle can be provided by the boost converter. In practice due to effect of power switch, rectifier diode and the equivalent series resistance of the inductor and capacitor can limit the voltage gain. Also, reverse recovery and electromagnetic interface problems are caused by the extreme duty cycle operation

There are various boosting techniques in which fundamental energy storing elements or transformers with switch and diode are utilized in the circuit. These techniques include Switched capacitor, Combination technique, Interleaving technique, Voltage lift technique etc. First three techniques have its own merits and demerits depending upon its applications, cost, complexity, power density, reliability and efficiency. Whereas, Voltage lift has advantage of less voltage and current stress on elements and higher voltage gain using fewer no of elements. When the proposed boost



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converter is compared with conventional boost converter at50% duty cycle the output voltage gain of proposed converter is two times of conventional converter.

II. RELATED WORK

In R.D. Middlebrooks from Caltech in 1977 published the model for DCto DC converters which are used today. In 1980's the use of field effect transistors(FET's) increased the efficiency of DC- DC converters. Later, literature has reported various voltage boosting techniques which incorporates fundamental energy storing elements (inductors and capacitors) or transformers in conjunction with switches and diodes. These techniques include switched capacitor (charge pump), voltage multiplier, magnetic coupling, voltage lift (switched inductor) etc. each has its own merits and demerits depending on application, cost, complexity, power density, reliability and efficiency.

Shiyu Zhang, Jianping Xu, Ping Yang, their work was based on the traditional voltage-lift-technique and they introduced amodified voltage-lift cell. A single-switch high gain quadratic boost converter is obtained by applying the modified voltage-lift cell to quadratic boost converter, the voltage gain of the converter is improved and the switch voltage stress of the converter is also reduced. The operation principle of the quadratic boost converter with modified voltage-lift cell is analyzed and Compared with quadratic boost converter and the other single-switch high gain boost converter, the voltage gain of quadratic boost converter with modified voltage-lift cell is highest, and the switch voltage stress of quadratic boost converter with modified voltage-lift cell is highest, and the switch voltage stress of quadratic boost converter with modified voltage-lift cell is highest, and the switch voltage stress of quadratic boost converter with modified voltage-lift cell is highest.

M. Shahir, M.A. Azar and B. Taher introduced a new structure for non-isolated boost DC- DCconverter based onvoltage-lift (VL) technique. The proposed structure provided satisfied output voltage onlywith one switch. The voltage gain along with voltage and current relation of each element in continuous current mode (CCM) is also mentioned. In addition, the current and voltage stress are analyzed individually. 5Also, the proposed converter is comparedwith some presented converter in term of number of components and voltage gain in CCM

III. METHODOLOGY

Project model consist of main equipment which includes a DC power supply or asolar panel, DC- DC converter, astable multi vibrator circuit and a resistive load. From the figure 1.1 it is clear that sun ray is trapped by solar panel and gives output as DC. Converter is used to convert DC output of solar panel into boosted DC. IGBT is used as a switch for this converter. switching pulses is given to the converter which is generated by astable multivibrator. PWM technique is used to generate switching pulses. Hence it is sufficient to run the resistive load.

Modes of Operation

Mode 1 $[0 \le t \le Ton]$

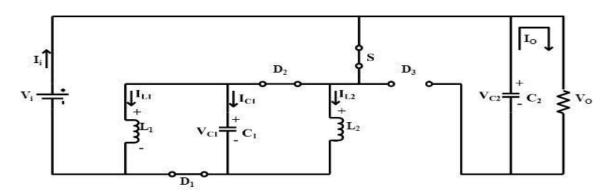


Figure 2.2 Proposed Boost Converter for TON

The equivalent circuit of this time interval is shown in figure 2.3. When the switch S is turned on, diodes D1 and D2 are forward biased and the diodeD3 is reverse biased. Thus the inductors L1 and L2 and capacitor C1 are connected in parallel. The input voltage source (Vi) is also connected to it in parallel. During this time interval, the stored energy of



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inductors L1 and L2 are increased and the current through them are reached to their maximum values. Also the stored energy of capacitor C1 is increased to its maximum value. Meanwhile the load current is provided by capacitor C2. As a result, the voltage and stored energy of capacitor C2 is gradually decreased.

Mode 2 [TON< t < TOFF]

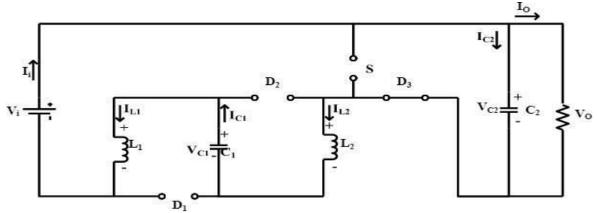
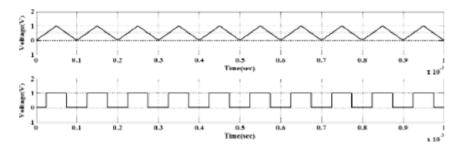


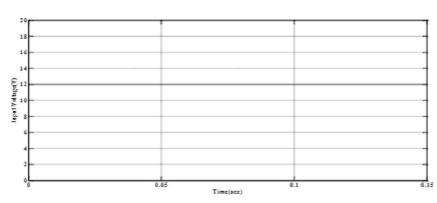
Figure 2.3 Proposed Boost Converter for TOFF

The equivalent circuit of this time interval is shown in figure 2.2. When the switch S is turned off, diode D3 is forward biased and the diodes D1 and D2 are reverse biased. Thus the inductors L1 and L2, capacitor C1 and the input voltage source (Vi) are connected in series. During this time interval, the stored energy of inductors L1 and L2, capacitor C1 are decreased. Meanwhile, the stored energy and voltage of capacitor C2 is increased to its maximum value and the load current is provided by series combination of elements and source.

IV. SIMULATION RESULTS



(a)



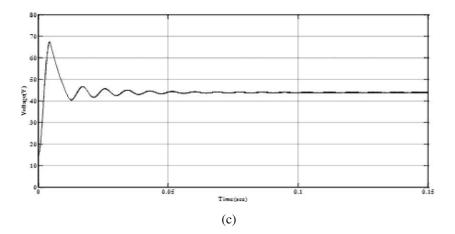
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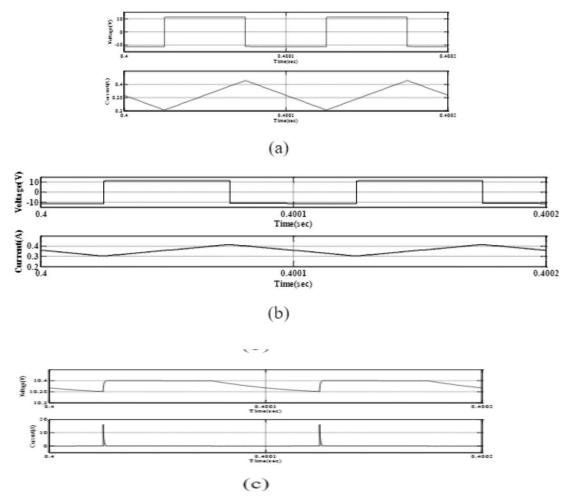
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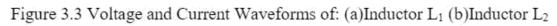
Flgure 3.2 (a) Generation of Gate Pulses by PWM Technique (b)Input Waveform (c)Output Waveform

The generation of gate pulses by PWMis shown in figure 3.2(a). The rectangular pulses are generated by comparing triangular carrier signal with constant magnitude signal of 0.5 amplitude. Input waveform is shown in figure 3.2(b). Constant 12voltsis given as input to the converter. Output waveform is shown in figure 3.2(c). As shown in figure magnitude of output voltage is nearly four times as that of input voltage





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(d)

0.4901

(c)Capacitor C1 (d)Capacitor C2

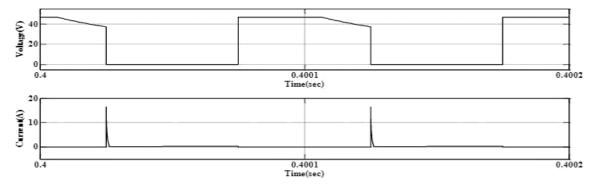


Figure 3.5 Voltage and Current Waveform of IGBT switch

The voltage and current waveforms of IGBTis shown in figure 3.5. Voltage of switch S is changing from 0 to -43V. The current of switch has a ripple of 16amps magnitude for avery short duration

V. CONCLUSION

A compactly designed single switch non-isolated boost converter based on voltage lift technique is proposed in this project .In our project less number of elements are used and using storage element feature output voltage is raised .Hence, the proposed converter is applicable for more boosting applications and can be used with less no. of solar panels to boost the voltage easily up to the system voltage .Thus ,it plays a greater role in development of renewable energy sources.

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